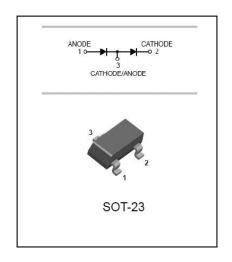


Dual series switching diode

FEATURES

- Fast switching speed Max:6ns
- High conductance
- Connected in series
- Surface mount package ideally suited for automatic insertion



APPLICATIONS

• Small signal switching

MAXIMUM RATING @ Ta=25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Value	Unit
Non repetitive peak reverse voltage	V _{RM}	80	V
Repetitive peak reverse voltage Working peak reverse voltage DC Reverse voltage	V _{RRM} V _{RWM} V _R	70	V
Peak forward surge current @t=1.0s @t=1.0µs	I _{FSM}	1 4.5	mA
Forward current	I _F	250	mA
Power dissipation	P _d	300	mW

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MMBD1203

ELECTRICAL CHARACTERISTICS @ Ta=25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V _(BR)	I _R = 100μA	70		V
Reverse voltage leakage current	I _R	V _R =70V		2.5	μΑ
Forward voltage	V _F	$I_F=1mA$ $I_F=10mA$ $I_F=50mA$ $I_F=150mA$		715 855 1000 1250	mV
Diode capacitance	C _D	V _R =0V f=1MHz		1.5	pF
Reverse recovery time	t _{rr} ‰	$I_F = I_R = 10 \text{mA}$ $V_R = 5V$ $R_C = 100\Omega$		6	nS

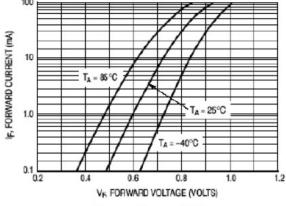


Figure 1 Forward Voltage

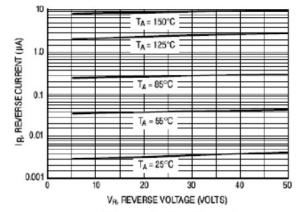


Figure 2. Leakage Current

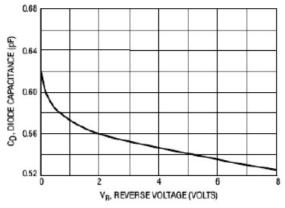


Figure 3. Capacitance

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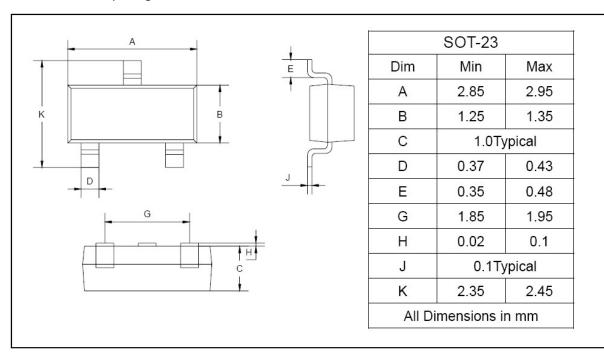


MMBD1203

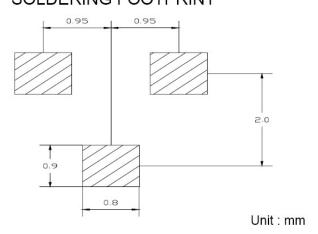
PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



SOLDERING FOOTPRINT



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